

Prediction of nanotexture transfer and optical gains in ultra-thin textured CIGS solar cells

ARCIGS-M

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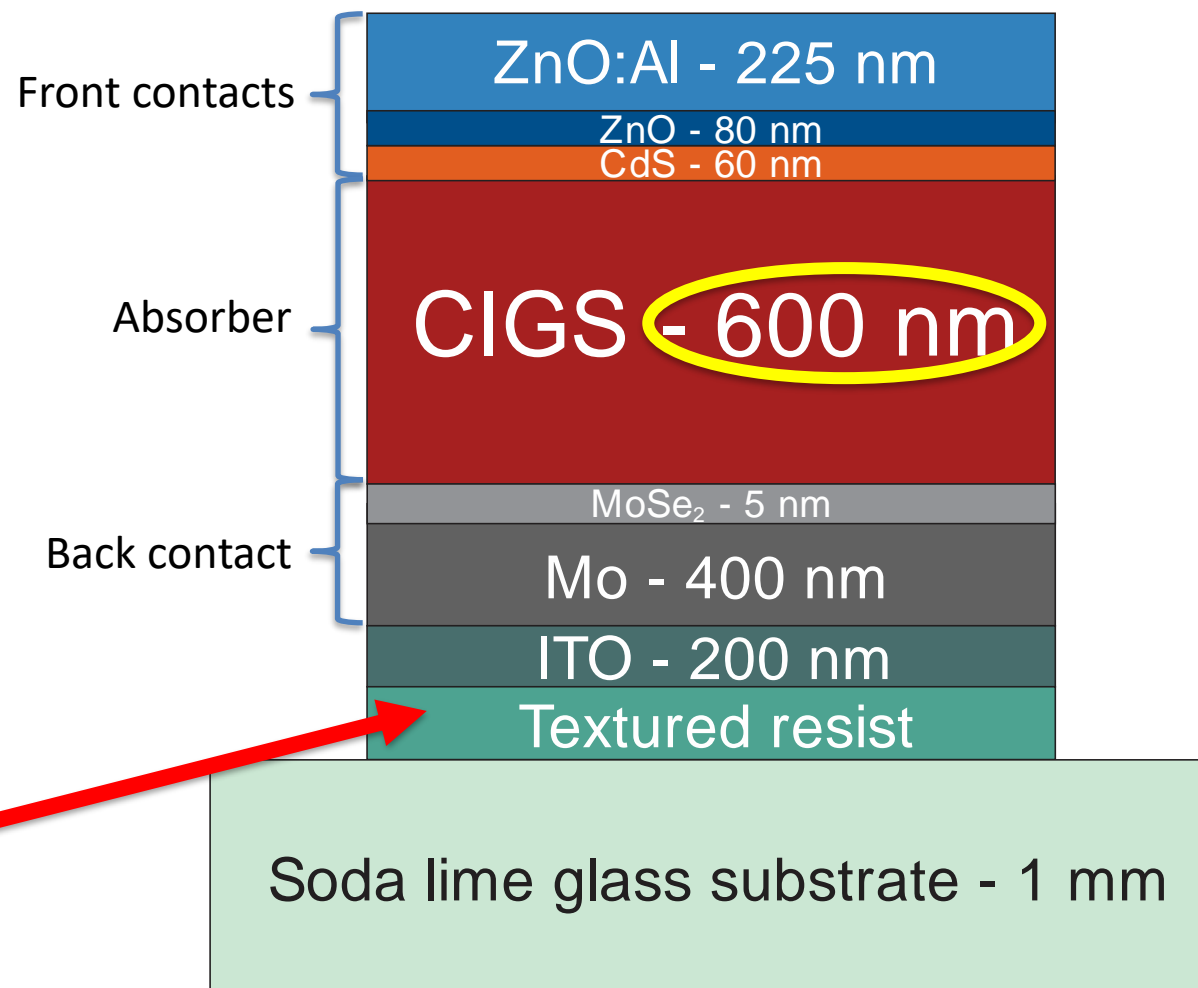
TNO innovation
for life

Outline

- Introduction
- Textured substrates & layer by layer texture transfer
- Optical modeling
- Results
- Conclusions

Ultra-thin CIGS solar cell (on textured substrate)

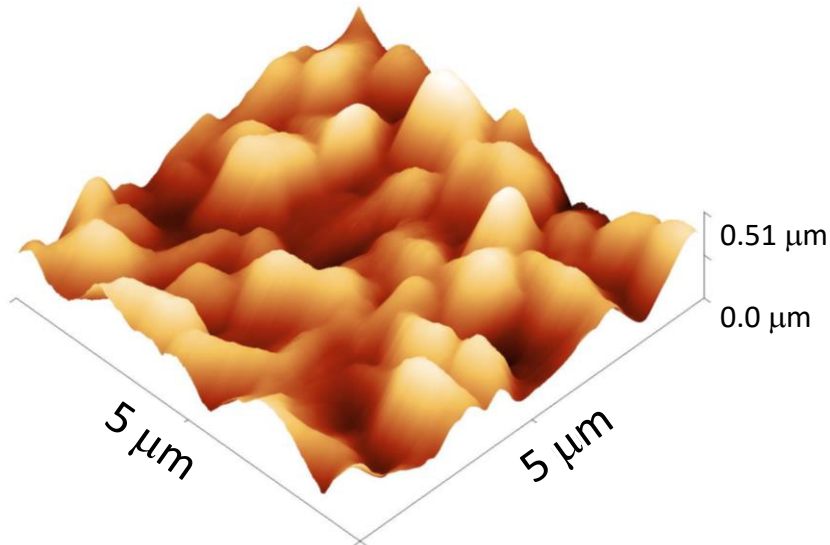
- Thin film CIGS solar cell technology:
 - › Record efficiency of 23.35 %
- Usual thickness of CIGS $\geq 1.8 \mu\text{m}$
 - › Consumption of scarce materials (e.g. In, Ga)
 - › Longer deposition times (thick layer)
- **Our aim: usage of ultra-thin ($\leq 600 \text{ nm}$) CIGS absorbers $\rightarrow J_{\text{sc}}$ reduction**
 - › Sol-gel SiO_2 based lacquer with NIL imprinted texture for light management



AFM measurements of textured substrates

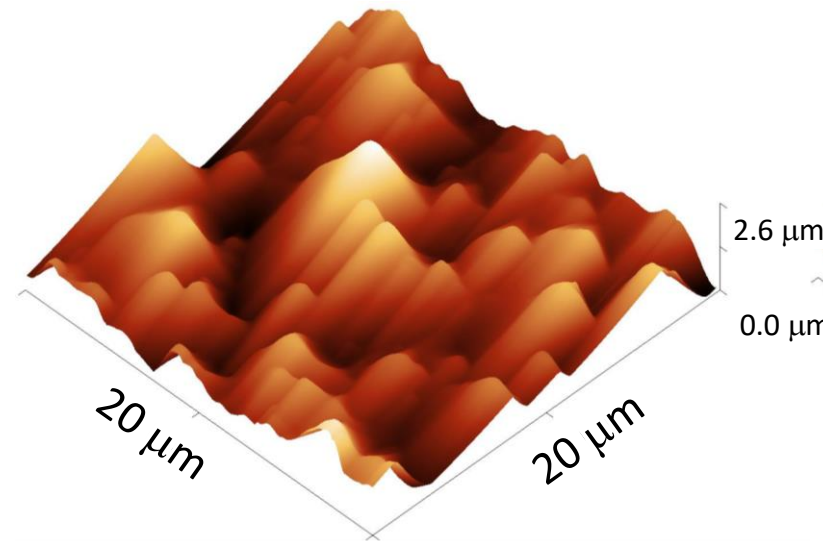
3 types of textured substrates: SLG-textured resist-ITO surface

Texture M –
Random nano pyramids



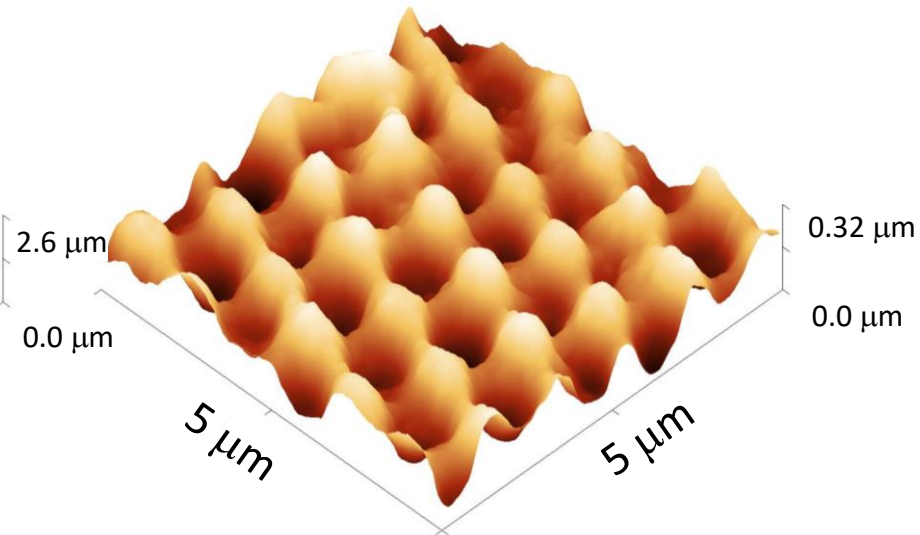
$\sigma_{\text{rms}} = \sim 85 \text{ nm}$
 $L_{\text{autocorrelation}} \sim 350 \text{ nm}$

Texture W –
Large random pyramid texture



$\sigma_{\text{rms}} = \sim 400 \text{ nm}$
 $L_{\text{autocorrelation}} \sim 1500 \text{ nm}$

Texture H –
Periodic texture

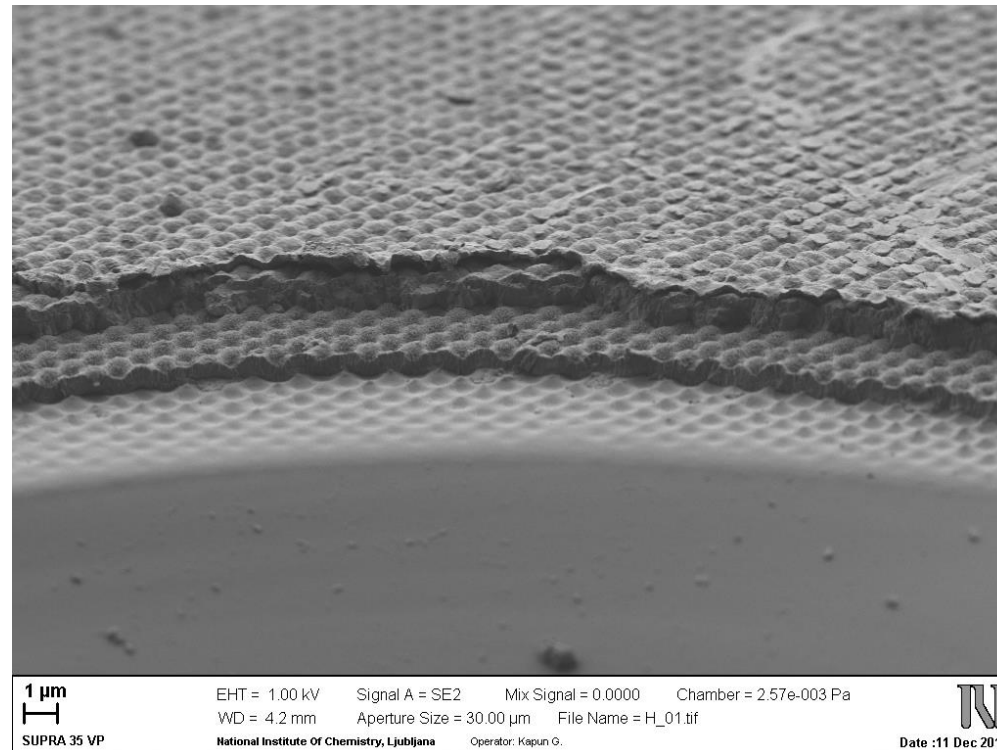


$\sigma_{\text{rms}} = \sim 60 \text{ nm}$
Period $\sim 1000 \text{ nm}$

Layers growth on textured substrates

Cross sectional SEM images of CIGS cell structures deposited on textured substrates

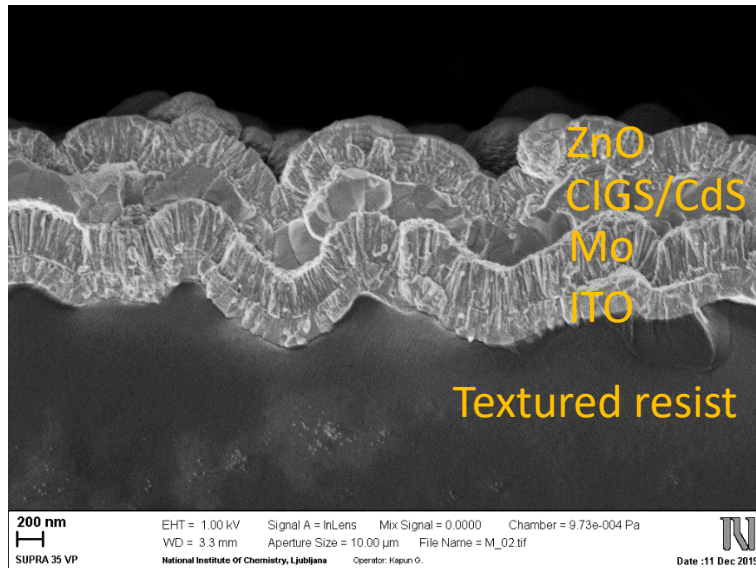
Texture **H** –
Periodic texture



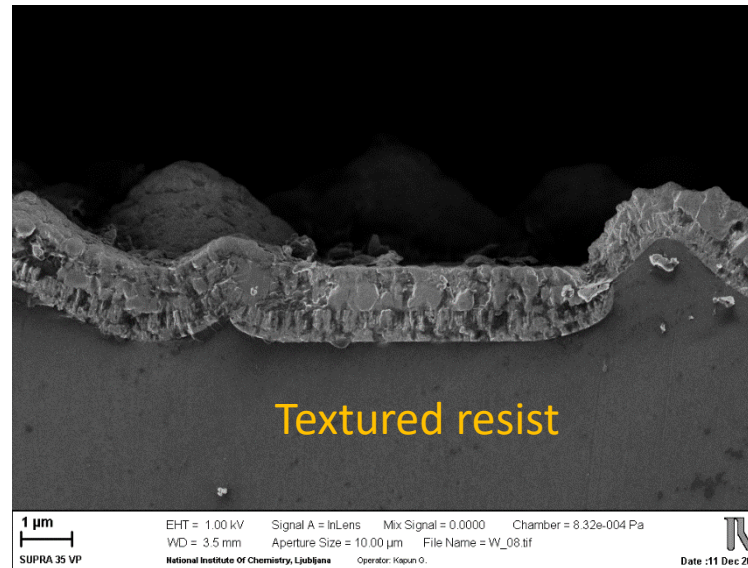
Detailed view on texture transfer

Cross sectional SEM images of CIGS cell structures deposited on textured substrates

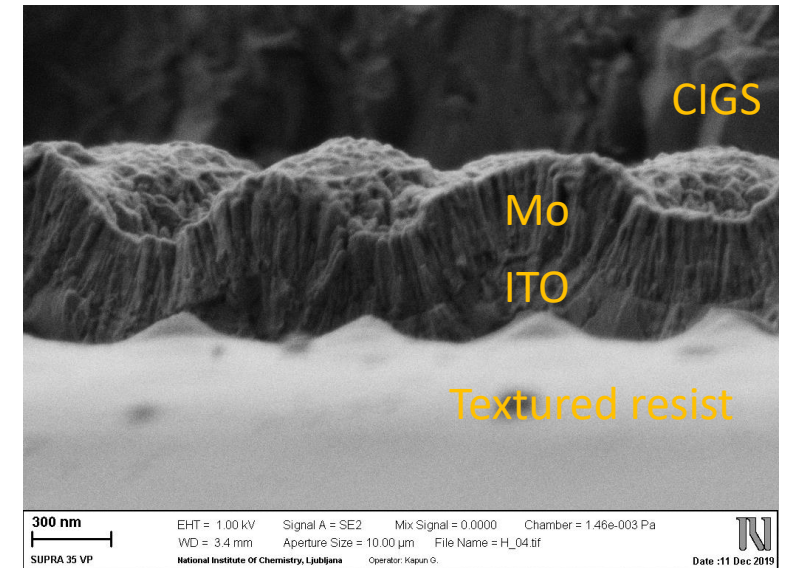
Texture M –
Random nano pyramids



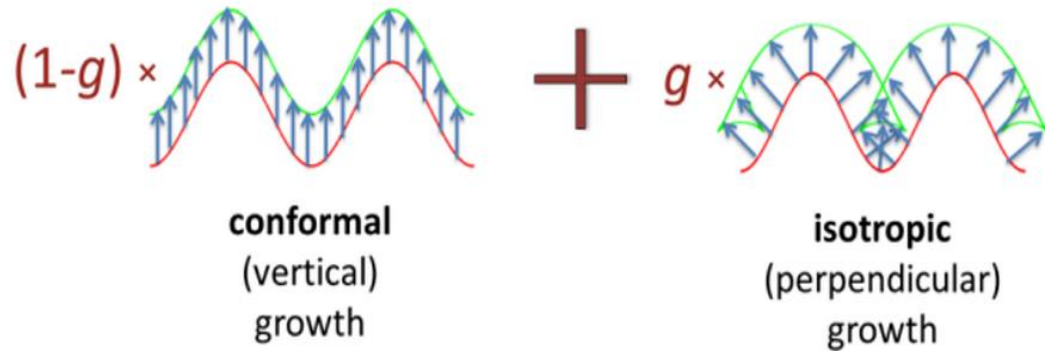
Texture W -
Large random pyramid texture



Texture H –
Periodic texture

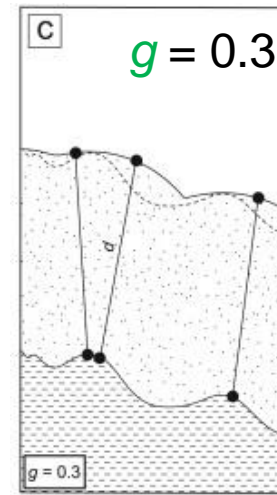
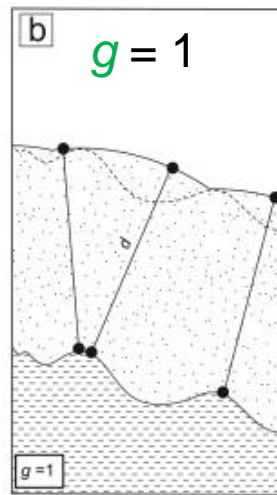
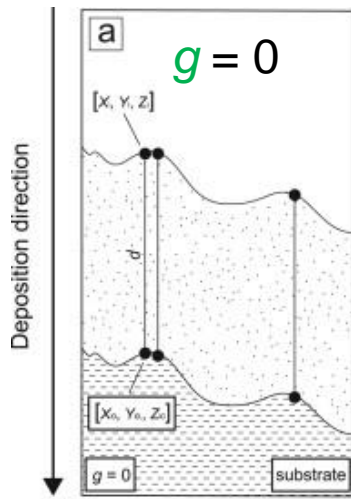


3D model of non-conformal growth - concept



$g = 0 \Rightarrow$ fully conformal growth

$g = 1 \Rightarrow$ fully isotropic growth



$g = 0.3$ means more conformal than isotropic growth

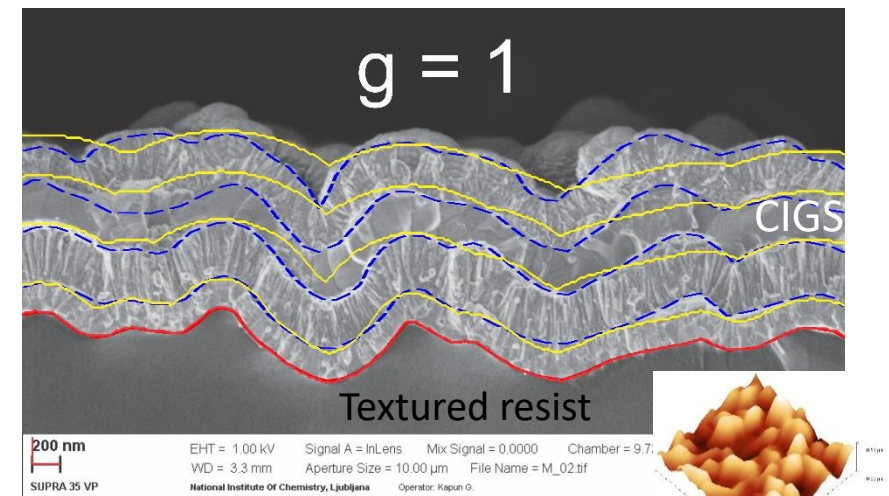
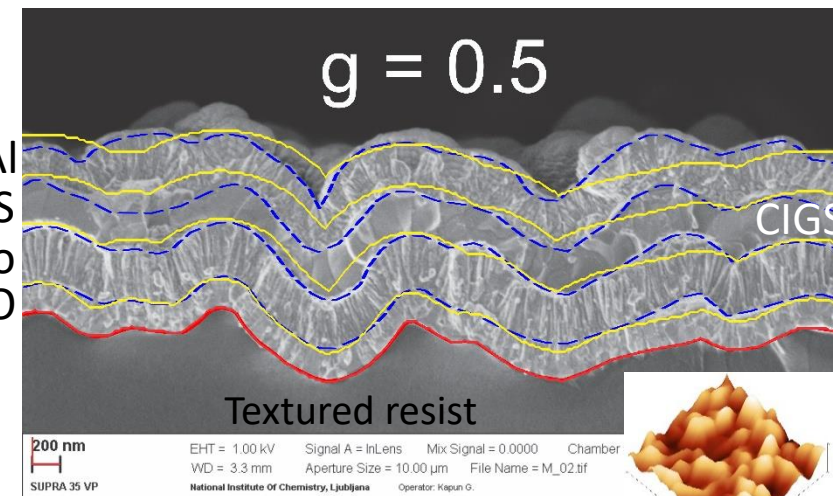
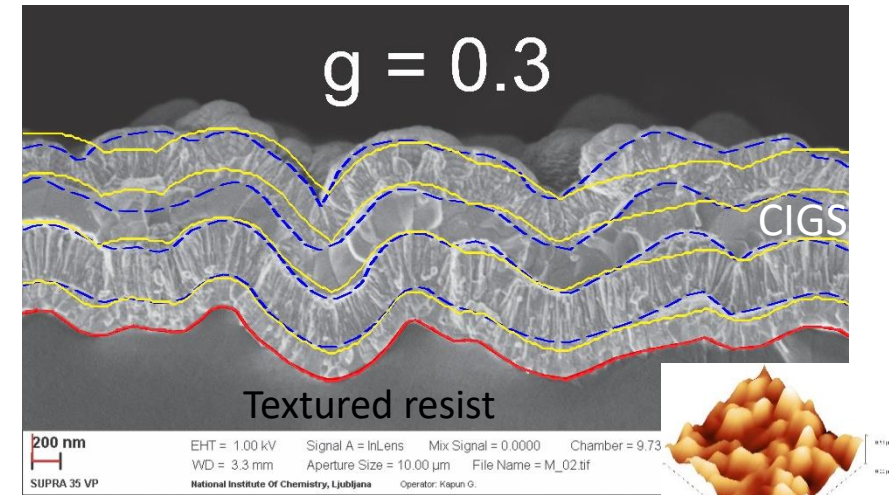
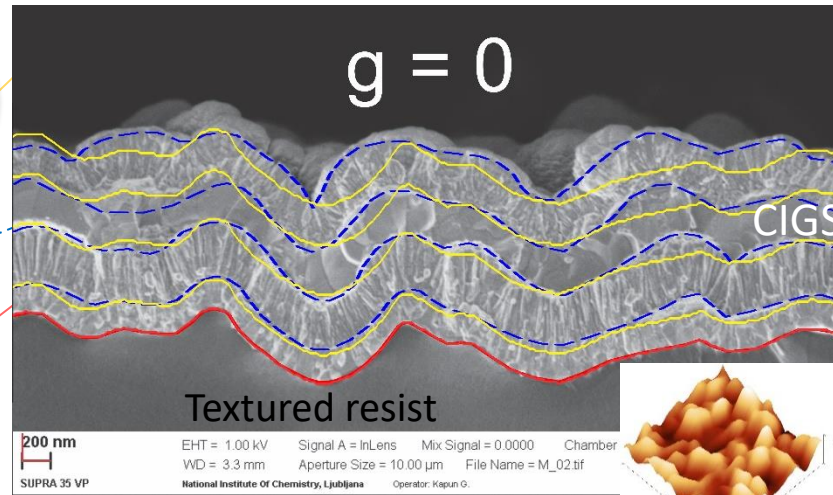
Texture transfer prediction - Random nano pyramids – M

g	Deviation (nm)*
0.0	108
0.1	96
0.2	87
0.3	83
0.4	84
0.5	86
1	91

Model Prediction (Yellow)

Layer interfaces

Initial layer

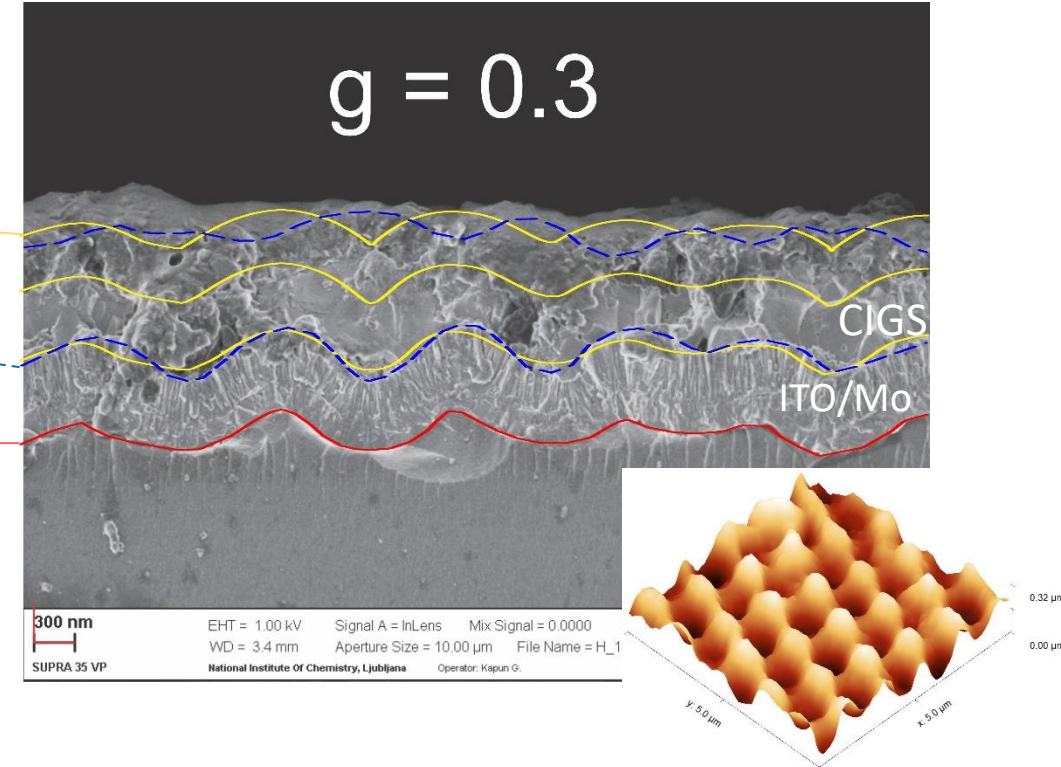
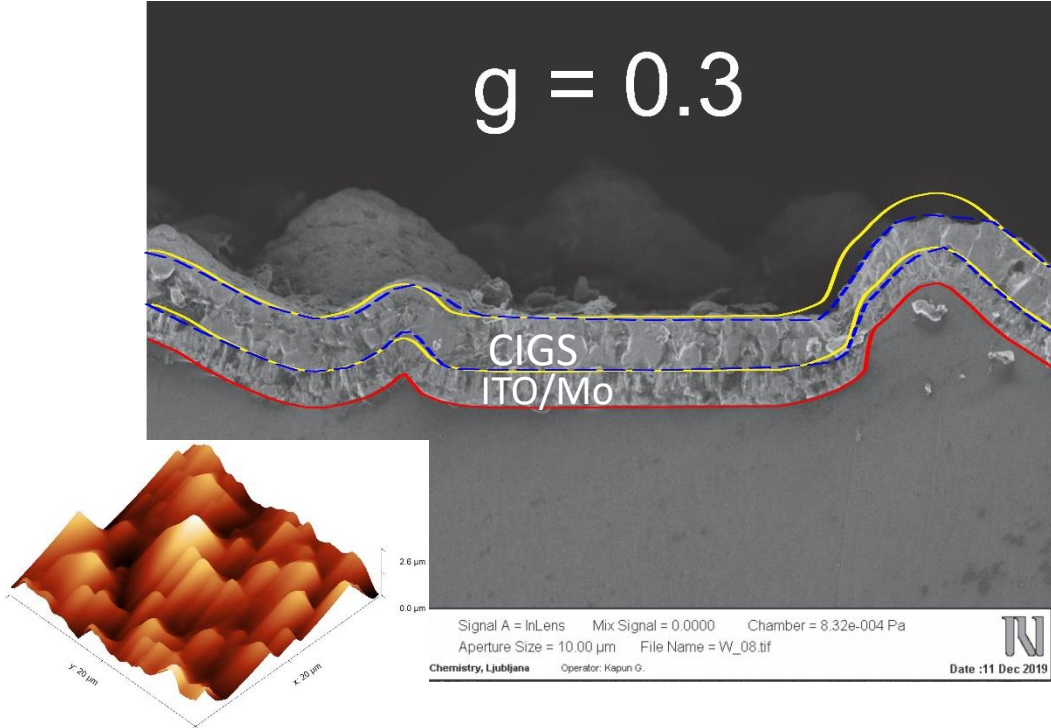


$$* \sqrt{\frac{\sum_{i=1}^n (y_{model\ prediction}(i) - y_{layer\ interface}(i))^2}{n}}$$

Texture transfer prediction

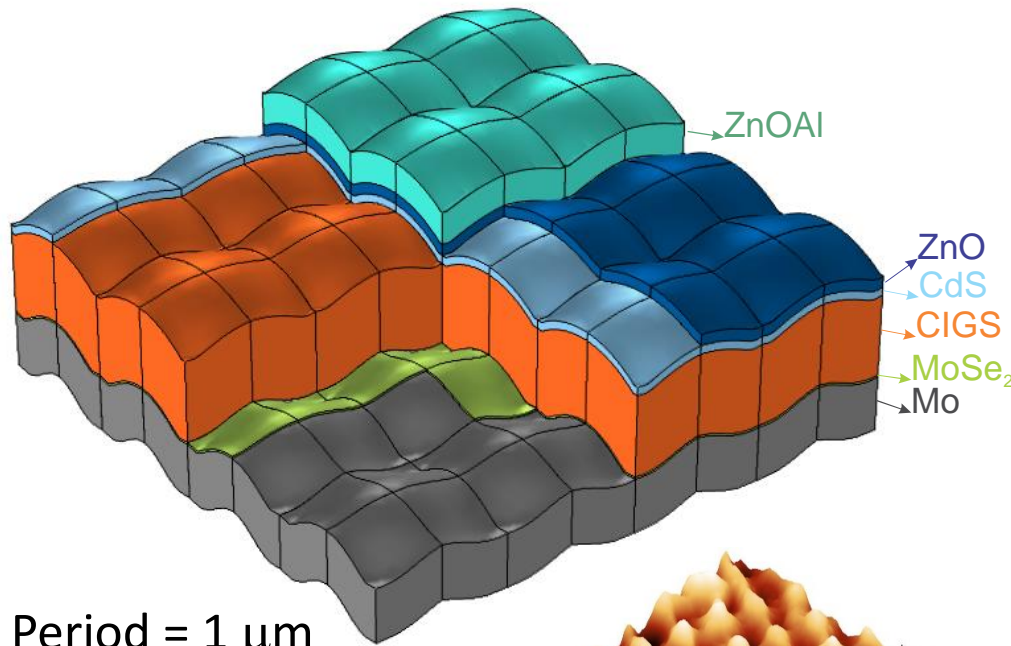
Texture W -
Large random pyramid texture

Texture H -
Periodic texture

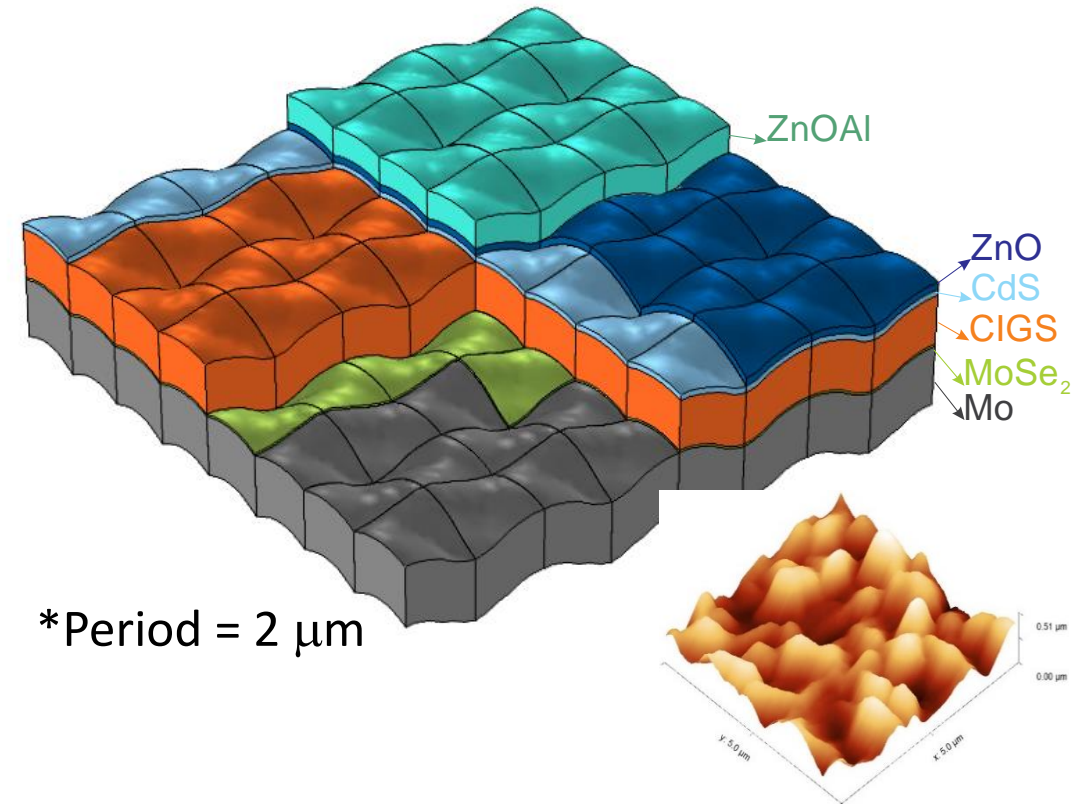


Modelled texture transfer in 3-D used in optical simulations

Periodic nano texture - H

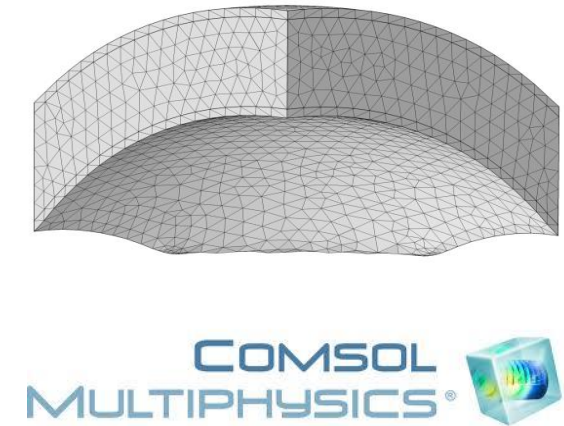
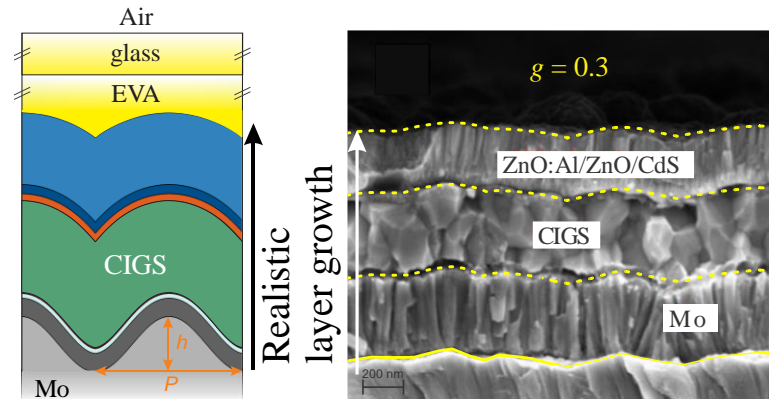


Random nano pyramids - M

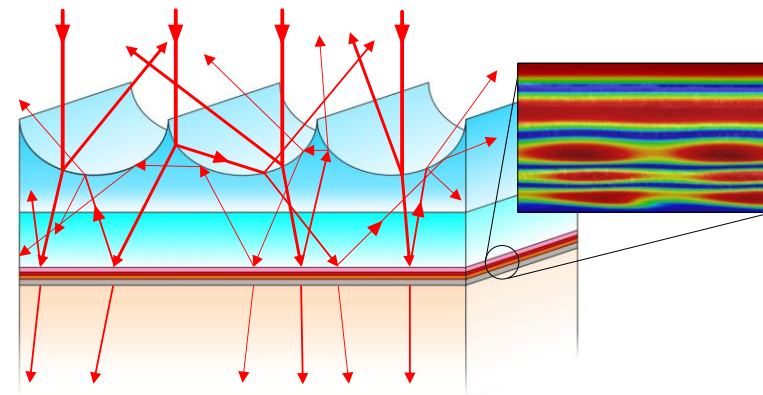


Optical modelling & simulations

- Nano-sized internal textures:
 - › Realistic layer growth
 - › 3D Finite Element Method (FEM)
 - › COMSOL Multiphysics Simulator



- Micro-sized textures:
 - › 3D Combined Ray Wave Optics
 - › *CROWM simulator



*Informacije MIDE M, nr. 41 (2011) pp. 264-271

Model of texture transfer

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optical data and thicknesses of layers

+

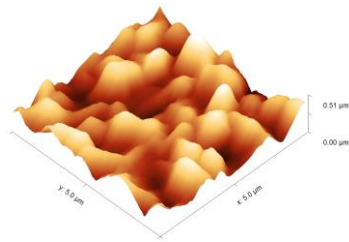
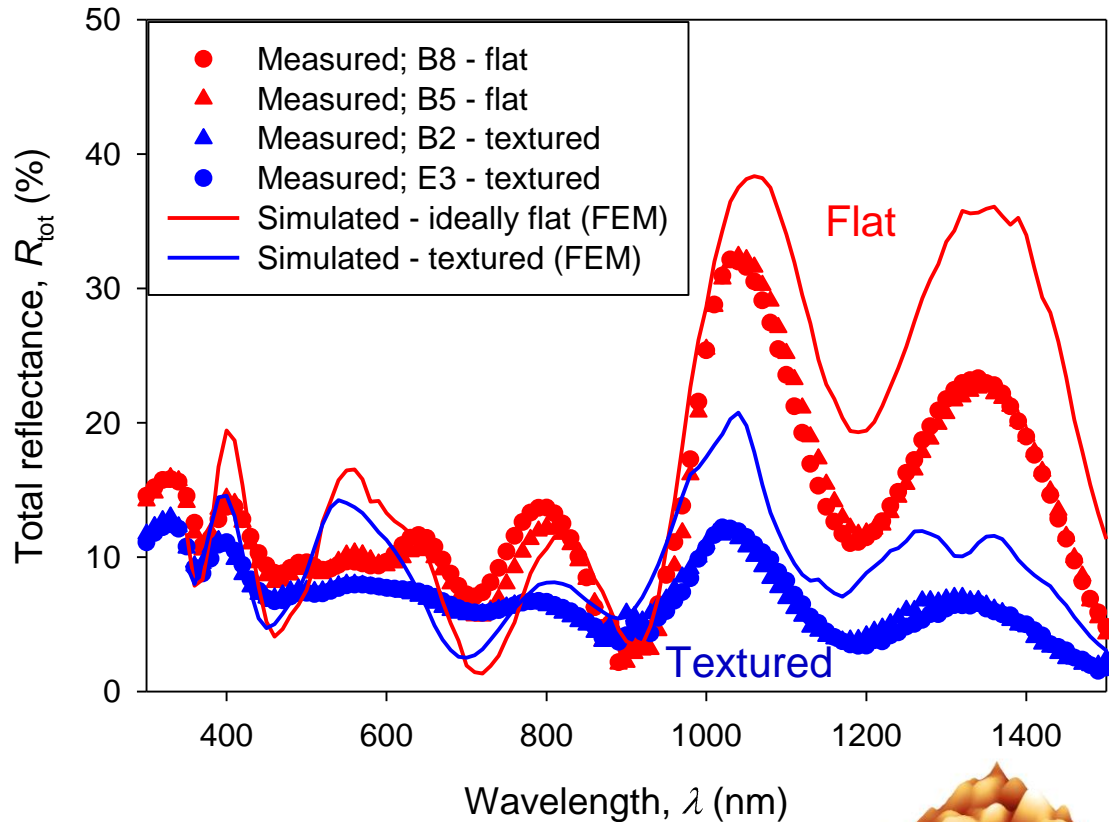
optical simulations with FEM or combined wave & ray optics



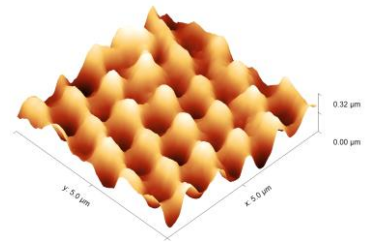
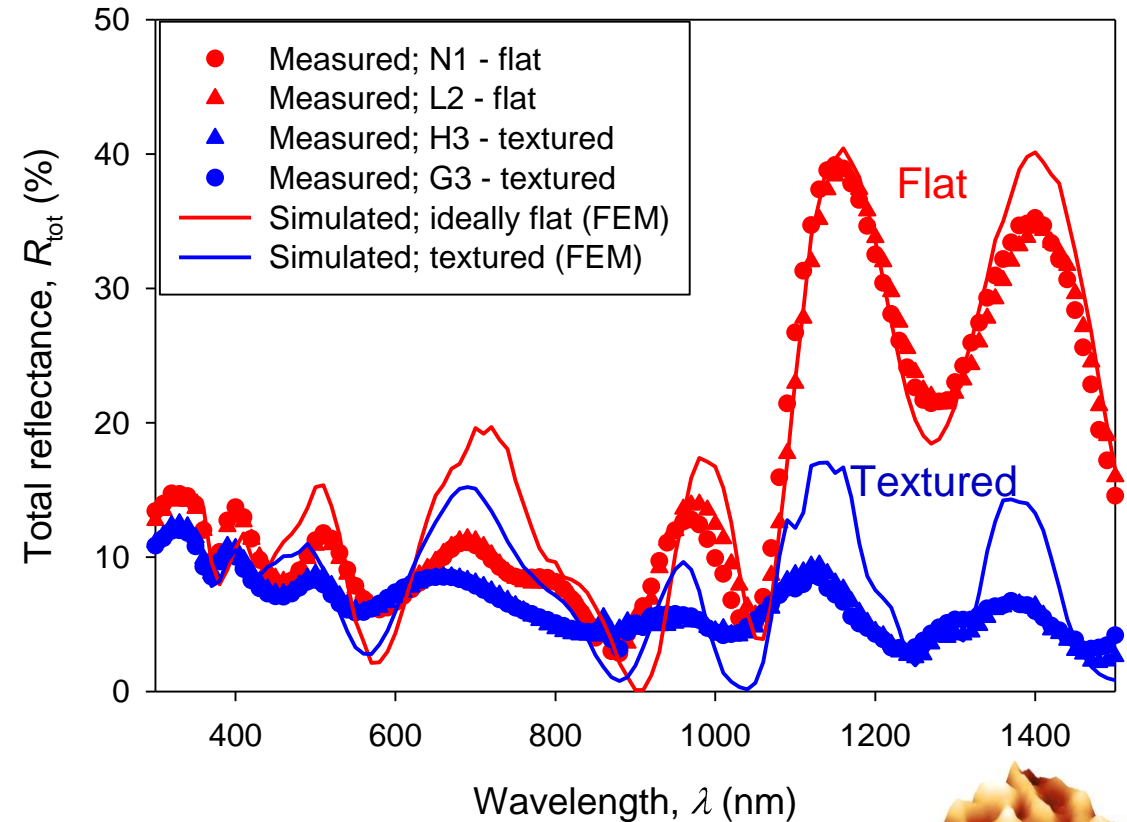
prediction of EQE and J_{sc} + analysis&optimization
(assuming certain carrier extraction rate)

R measurements & simulations

Random nano pyramids – **M**

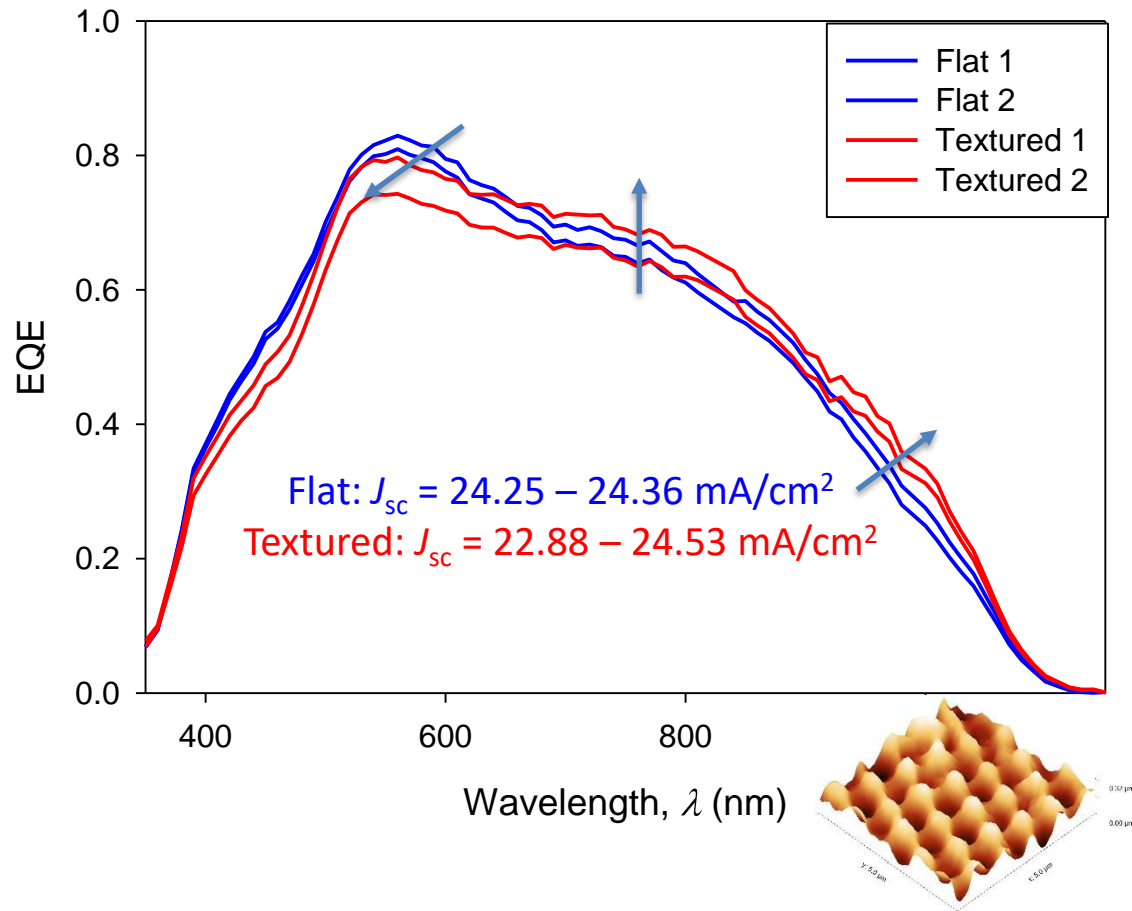


Periodic nano texture - **H**

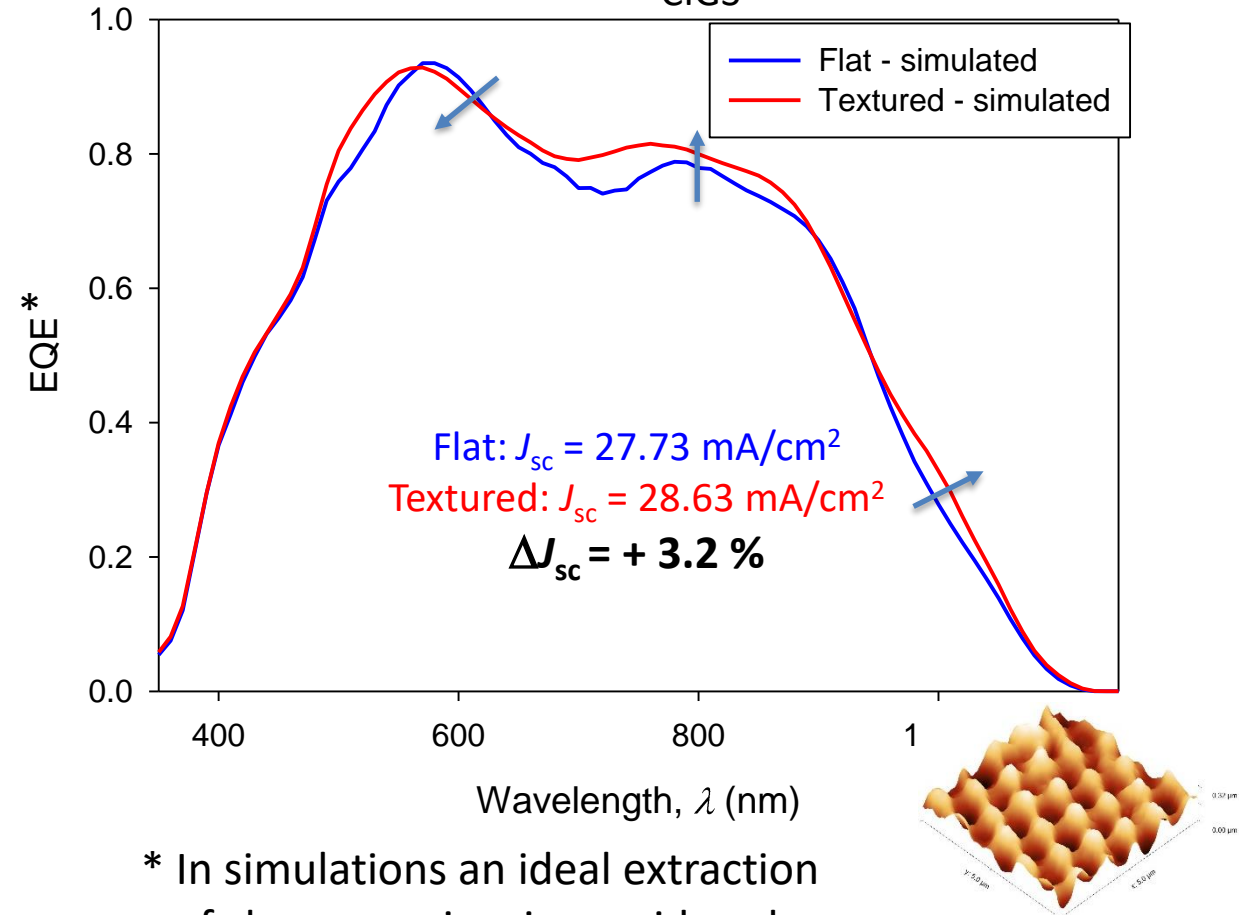


EQE measurements & simulations - Periodic nano texture - H

Measurements, $d_{\text{CIGS}} = 600 \text{ nm}$



Simulations, $d_{\text{CIGS}} = 600 \text{ nm}$

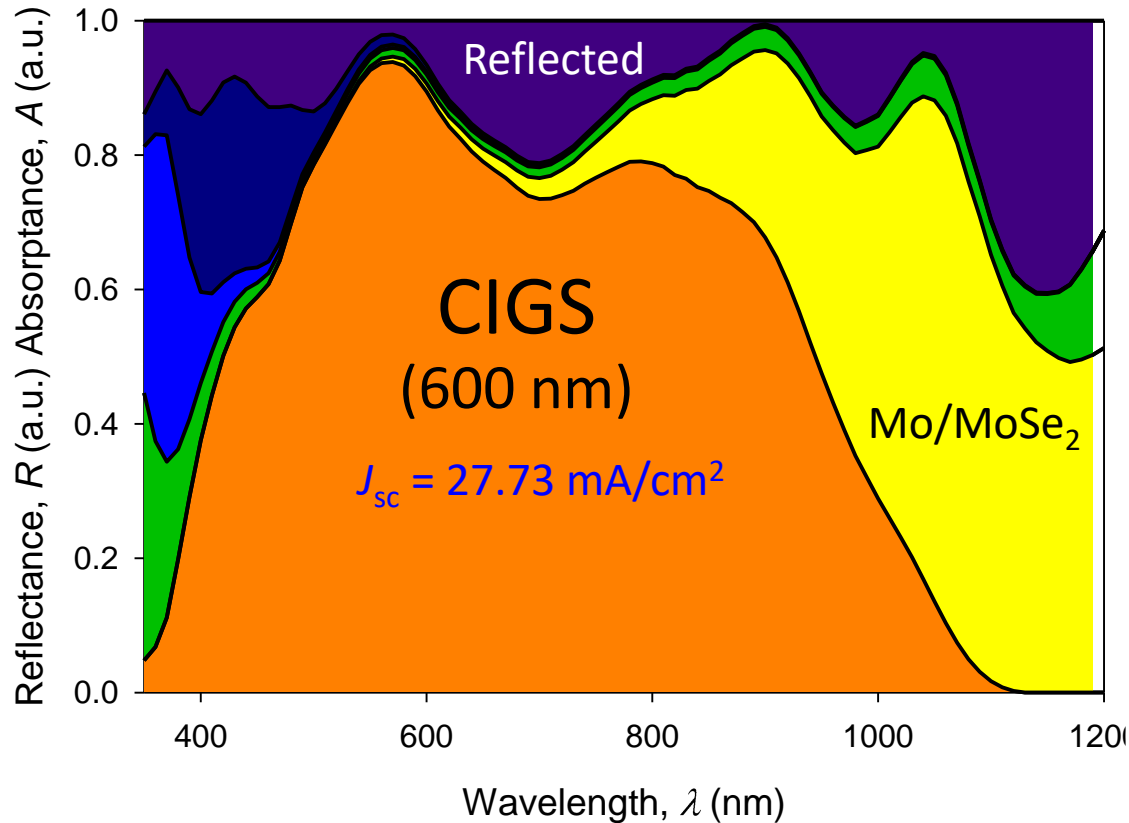


* In simulations an ideal extraction of charge carriers is considered

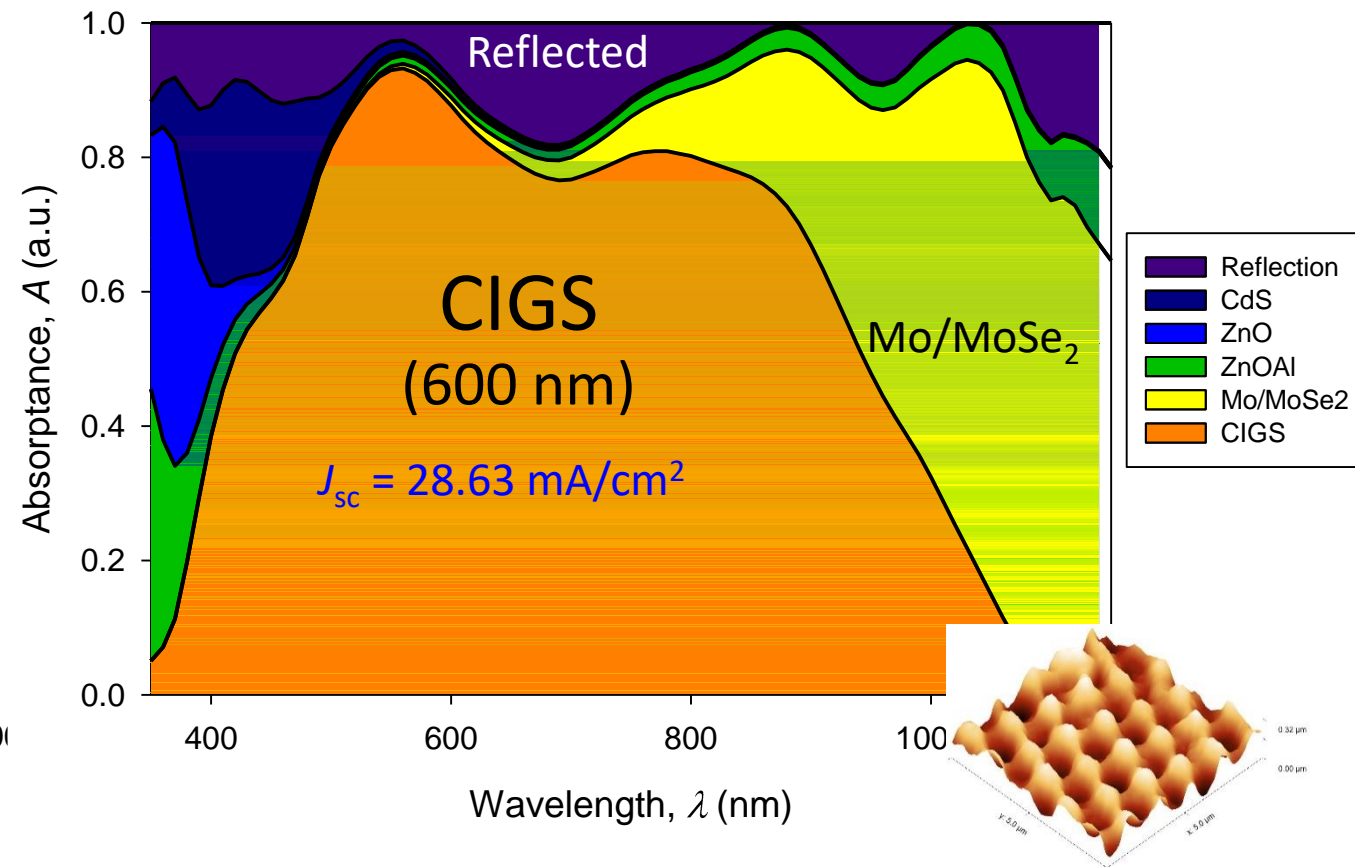
EQE & optical losses in cell – Mo contact

Simulations:

Ideally flat interfaces



Periodic nano texture - H

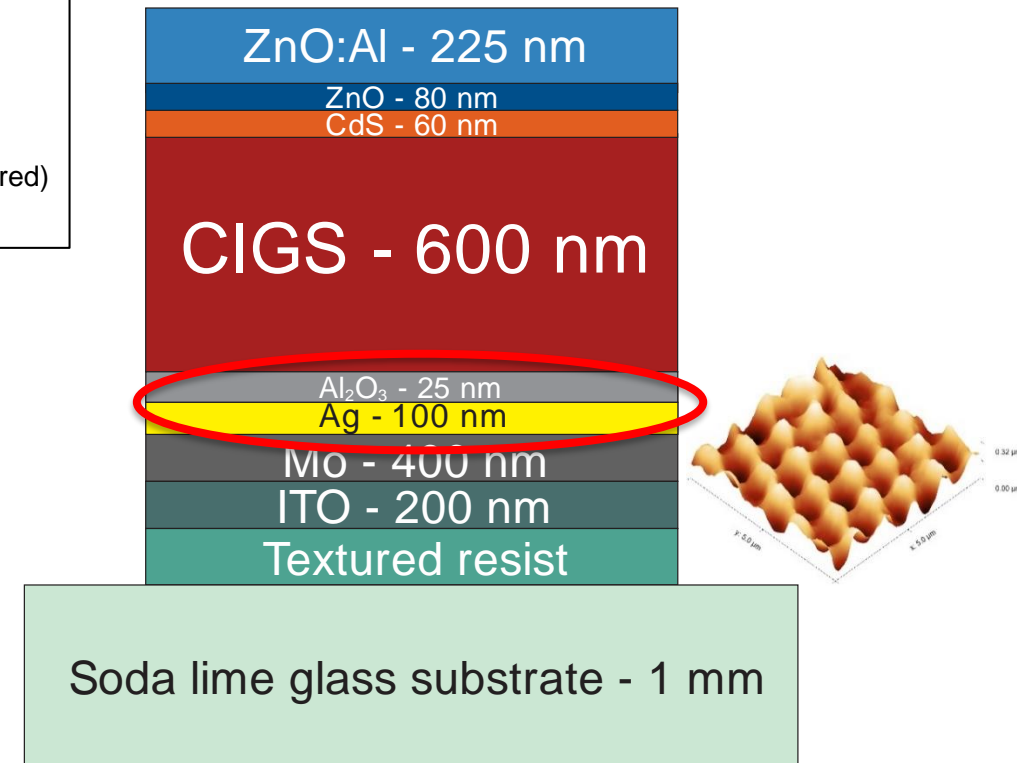
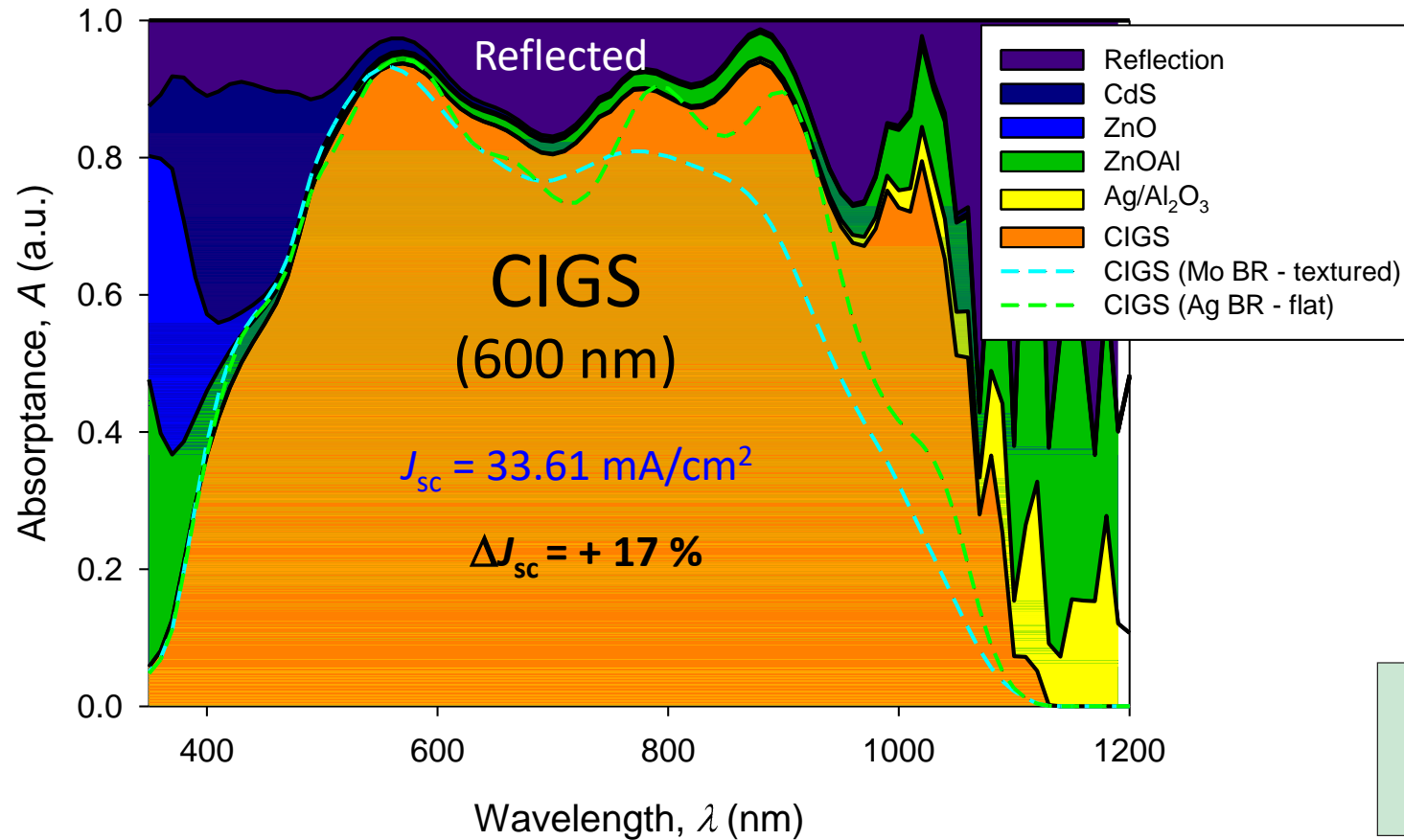


EQE & optical losses in cell – highly reflective back contact

Simulations:

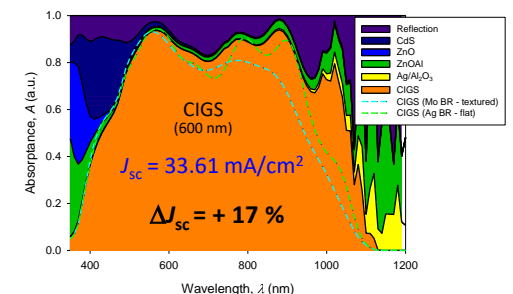
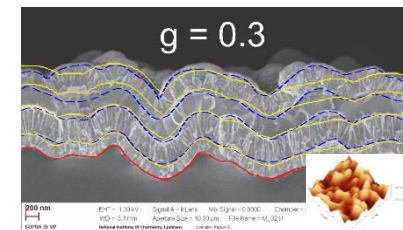
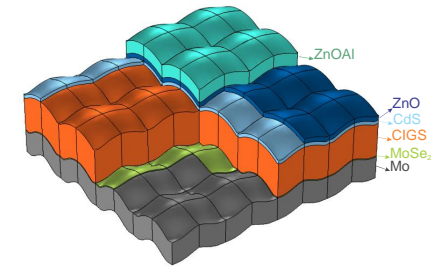
Periodic nano texture - **H**

+
texturization



Conclusions

- Using modelling and simulations supported by experimental verification we evaluated optical impact of internal textures (textured substrate) in ultra-thin CIGS solar cells
- Actual texture transfer (conformal + isotropic) of CIGS solar cell layers on top of a textured substrate is modelled and further used in optical simulations
- Main losses of textured and flat devices are evaluated and a solution with **an internal nanotexture and** highly reflective back contact (e.g. Ag) is proposed for more than 17 % increase in J_{sc} (compared to flat thin CIGS solar cell on Mo back contact)



More on modelling of ultra-thin CIGS:

- M. Kovacic et al., Sol. energy mater. sol. cells., 200 (2019) 109933
- M. Kovacic et al., Inf. Midem., Vol. 49, No. 3(2019), 183 – 190

Acknowledgements

The authors acknowledge the financial support of the H2020 project
ARCIGS-M (GA No. 720887 - H2020 NMBP-2016-2017)



European
Commission

Horizon 2020
European Union funding
for Research & Innovation



Thank you for your attention